Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

	Datenblatt / Data sheet	
Netz-Dioden-Modul Rectifier Diode Module	**DD98N**	Infineon Technologies Bipolar GmbH & Co. KG

Key Parameters

V_{DRM} / V_{RRM}	2000 - 2500 V
I_{FAVM}	98 A (T_C=100 °C)
I_{FSM}	2400 A
V_{T0}	0,82 V
r_T	2,0 mΩ
R_{thJC}	0,185 K/W
Base plate	20 mm
Weight	160 g

For type designation please refer to actual short form catalog

http://www.ifbip.com/catalog

Merkmale

- Druckkontakt-Technologie für hohe Zuverlässigkeit
- Industrie-Standard-Gehäuse
- Elektrisch isolierte Bodenplatte

Features

- Pressure contact technology for high reliability
- Industrial standard package
- Electrically insulated base plate

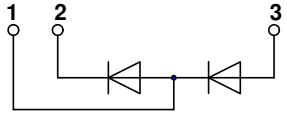
Typische Anwendungen

- Gleichrichter für Antriebsapplikationen
- Gleichrichter für UPS
- Batterieladegleichrichter

Typical Applications

- Rectifier for drives applications
- Rectifiers for UPS
- Battery chargers

content of customer DMX code	DMX code digit	DMX code digit quantity
type designation	1..18	18
serial number	19..23	5
internal production order number	24..31	8
material number	32..41	10
date code (YY/WW)	42..45	4
add on for date code	46	1



www.ifbip.com
support@infineon-bip.com

DD98N **DD98N..K..-K**

Elektrische Eigenschaften / Electrical properties

Höchstzulässige Werte / Maximum rated values

Periodische Spitzensperrspannung repetitive peak reverse voltages	T_{vj} = -40°C... $T_{vj\,max}$	V_{RRM}	2000 2200 2400 2500	V V
Stoßspitzensperrspannung non-repetitive peak reverse voltage	T_{vj} = +25°C... $T_{vj\,max}$	V_{RSM}	2100 2300 2500 2600	V V
Durchlaßstrom-Grenzeffektivwert maximum RMS on-state current		I_{FRMSM}	160	A
Dauergrenzstrom average on-state current	T_C = 100°C	I_{FAVM}	98	A
Stoßstrom-Grenzwert surge current	T_{vj} = 25 °C, t_P = 10 ms T_{vj} = $T_{vj\,max}$, t_P = 10 ms	I_{FSM}	2.400 2.000	A A
Grenzlastintegral I²t-value	T_{vj} = 25 °C, t_P = 10 ms T_{vj} = $T_{vj\,max}$, t_P = 10 ms	I²t	28.800 20.000	A²s A²s

Charakteristische Werte / Characteristic values

Durchlaßspannung on-state voltage	T_{vj} = $T_{vj\,max}$, i_F = 300 A	v_F	max. 1,53	V
Schleusenspannung threshold voltage	T_{vj} = $T_{vj\,max}$	$V_{(TO)}$	0,82	V
Ersatzwiderstand slope resistance	T_{vj} = $T_{vj\,max}$	r_T	2	mΩ
Sperrstrom reverse current	T_{vj} = $T_{vj\,max}$, v_R = V_{RRM}	i_R	max. 25	mA
Isolations-Prüfspannung insulation test voltage	RMS, f = 50 Hz, t = 1 sec RMS, f = 50 Hz, t = 1 min	V_{ISOL}	3,0 2,5	kV kV

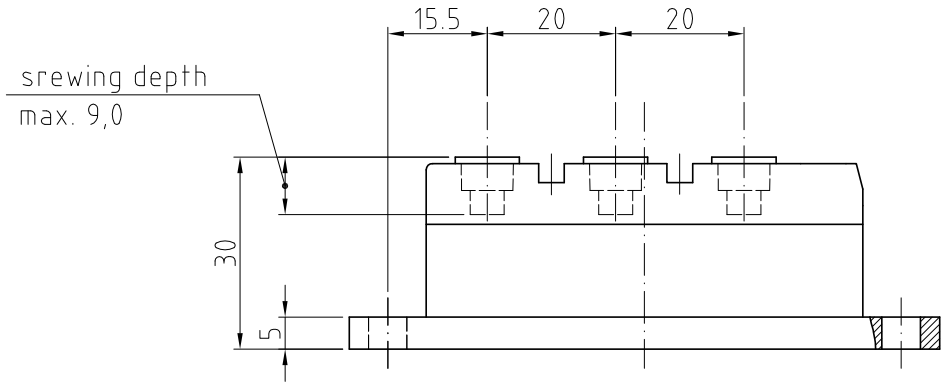
Thermische Eigenschaften / Thermal properties

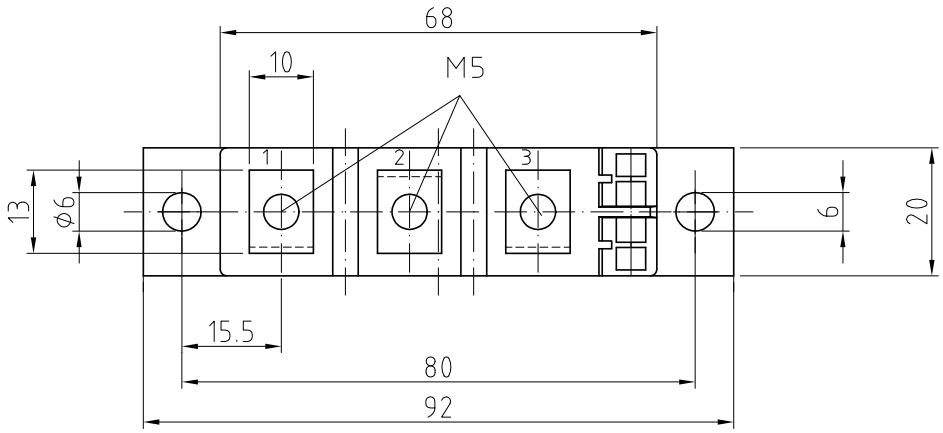
Innerer Wärmewiderstand thermal resistance, junction to case	pro Modul / per Module, Θ = 180° sin pro Zweig / per arm, Θ = 180° sin pro Modul / per Module, DC pro Zweig / per arm, DC	R_{thJC}	max. 0,195 max. 0,390 max. 0,185 max. 0,370	°C/W °C/W °C/W °C/W
Übergangs-Wärmewiderstand thermal resistance, case to heatsink	pro Modul / per Module pro Zweig / per arm	R_{thCH}	max. 0,05 max. 0,10	°C/W °C/W
Höchstzulässige Sperrschichttemperatur maximum junction temperature		$T_{vj\,max}$	150	°C
Betriebstemperatur operating temperature		$T_{c\,op}$	- 40...+150	°C
Lagertemperatur storage temperature		T_{stg}	- 40...+150	°C

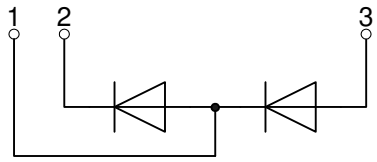
prepared by:	A.G.		date of publication:	23.05.2016
approved by:	M. S.		revision:	3.2

Mechanische Eigenschaften / Mechanical properties

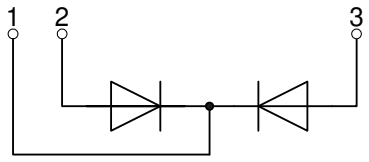
Gehäuse, siehe Anlage case, see annex			Seite 4 page 4	
Si-Element mit Druckkontakt Si-pellet with pressure contact				
Innere Isolation internal insulation			AlN	
Anzugsdrehmoment für mechanische Anschlüsse mounting torque	Toleranz ±15%	M1	4	Nm
Anzugsdrehmoment für elektrische Anschlüsse terminal connection torque	Toleranz ±10%	M2	4	Nm
Gewicht weight		G	typ. 160	g
Kriechstrecke creepage distance			15	mm
Schwingfestigkeit vibration resistance	f = 50 Hz		50	m/s²
	file-No.		E 83335	


15.5
20
20
srewing depth
max. 9,0
30
5


68
10
M5
1
2
3
13
ϕ6
6
20
15.5
80
92


1
2
3

DD


1
2
3

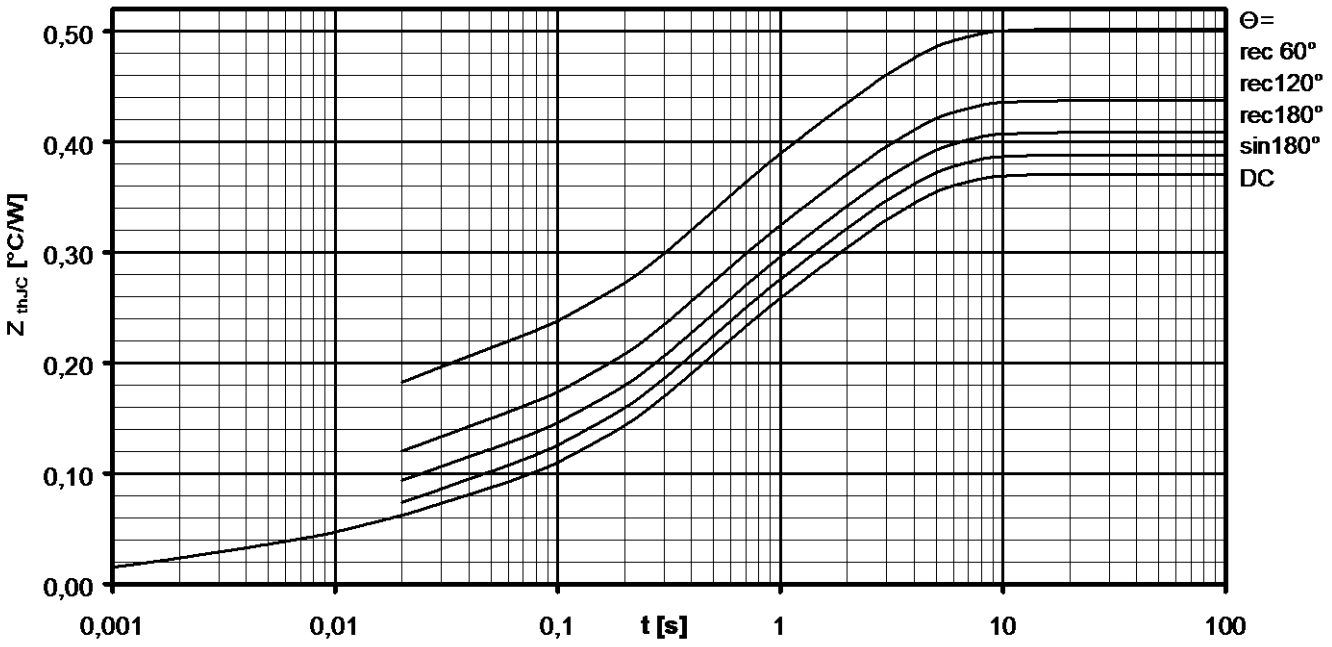
DD-K

Analytische Elemente des transienten Wärmewiderstandes Z_{thJC} für DC
Analytical elements of transient thermal impedance Z_{thJC} for DC

Pos. n	1	2	3	4	5	6	7
R_{thn} [°C/W]	0,0233	0,0433	0,134	0,17			
T_n [s]	0,00137	0,0175	0,325	2,11			

Analytische Funktion / Analytical function:

$$Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} \left(1 - e^{\frac{-t}{\tau_n}}\right)$$



Transienter innerer Wärmewiderstand je Zweig / Transient thermal impedance per arm Z_{thJC} = f(t)

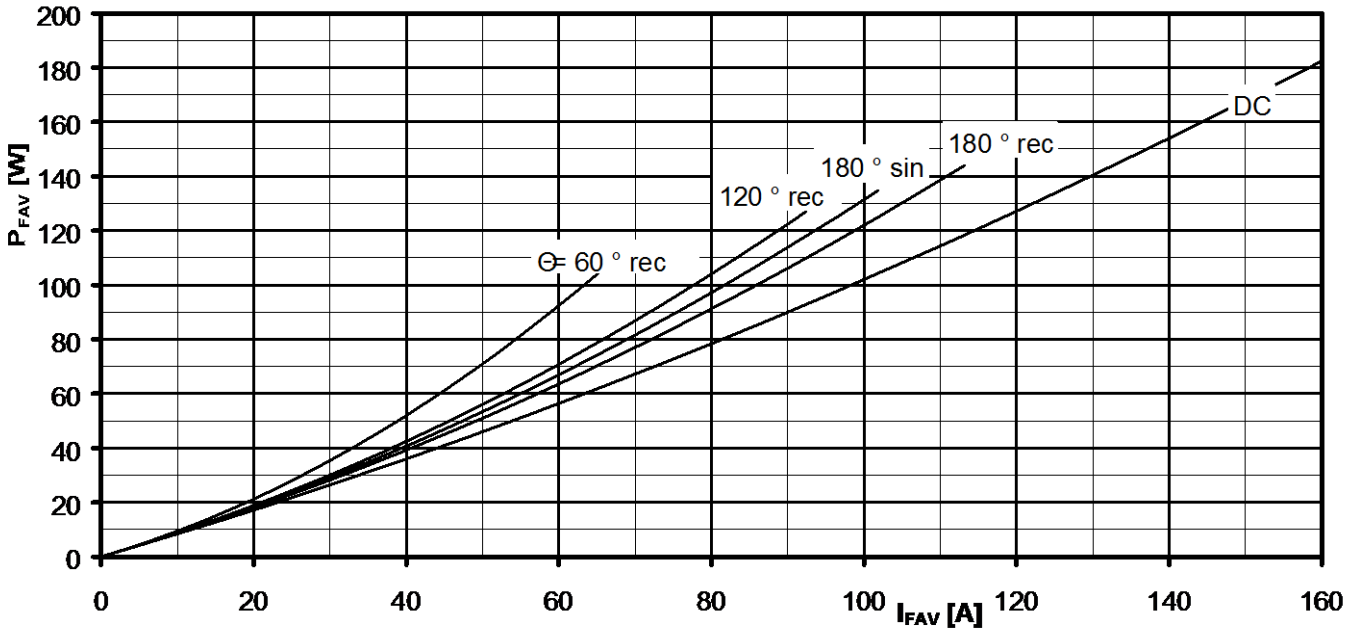
Parameter: Stromflußwinkel Θ / Current conduction angle Θ

Natürliche Kühlung / Natural cooling 3 Module pro Kühler / 3 modules per heatsink Kühler / Heatsink type: KM14 (50W)							
Analytische Elemente des transienten Wärmewiderstandes Z_{thCA} Analytical elements of transient thermal impedance Z_{thCA}							
Pos. n	1	2	3	4	5	6	7
R_{thn} [°C/W]	0,007	0,141	0,119	2,133			
T_n [s]	0,701	4,72	42,5	910			

Verstärkte Kühlung / Forced cooling 3 Module pro Kühler / 3 modules per heatsink Kühler / Heatsink type: KM14 (Papst 4650)							
Analytische Elemente des transienten Wärmewiderstandes Z_{thCA} Analytical elements of transient thermal impedance Z_{thCA}							
Pos. n	1	2	3	4	5	6	7
R_{thn} [°C/W]	0,007	0,141	0,119	0,583			
T_n [s]	0,701	4,72	42,5	249			

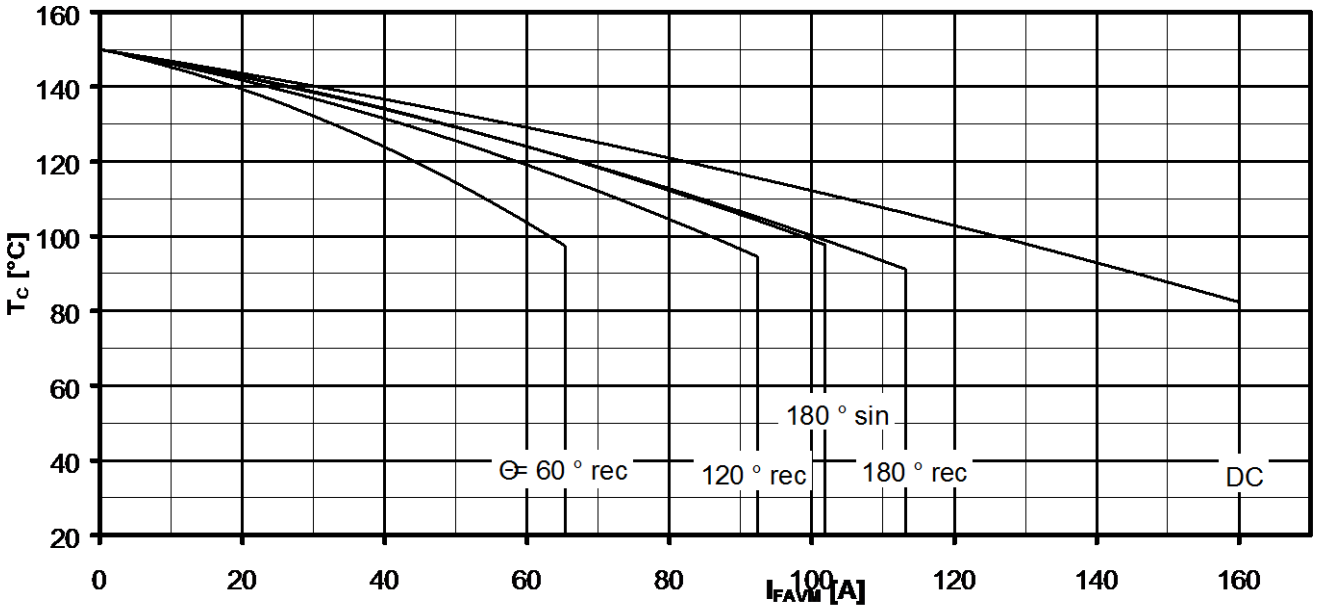
Analytische Funktion / Analytical function:

$$Z_{thCA} = \sum_{n=1}^{n_{max}} R_{thn} \left[1 - e^{\frac{-t}{\tau_n}} \right]$$



Durchlassverlustleistung je Zweig / On-state power loss per arm $P_{FAV} = f(I_{FAV})$

Parameter: Stromflußwinkel / Current conduction angle Θ

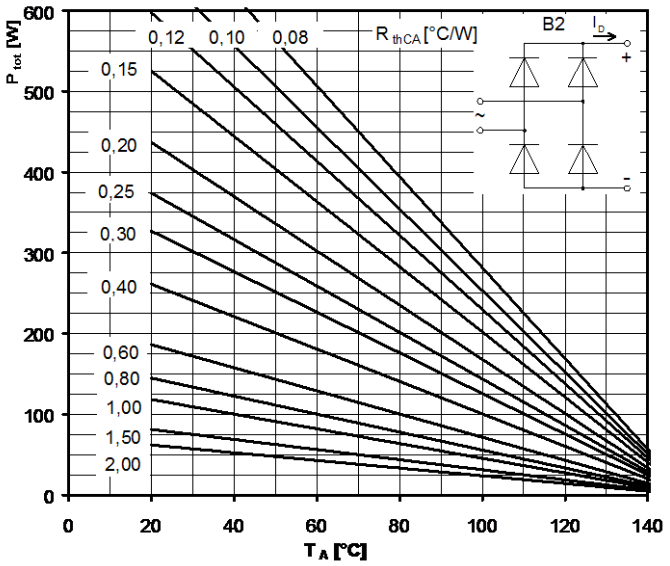


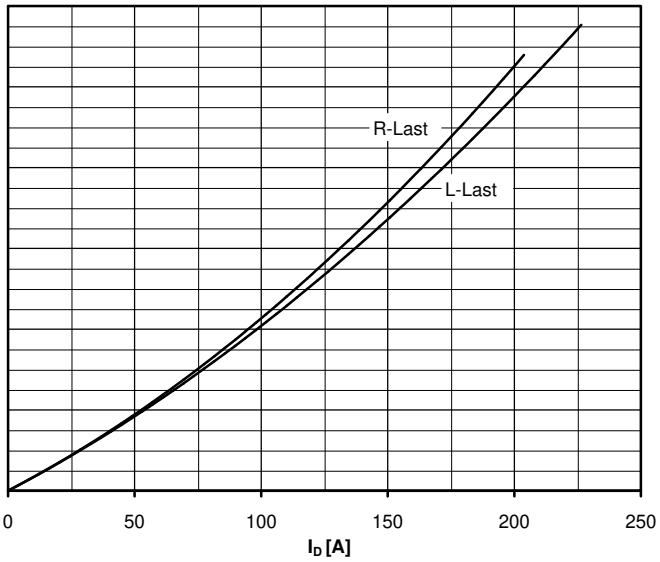
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{FAVM})$

Strombelastung je Zweig / Current load per arm

Berechungsgrundlage P_{TAV} (Schaltverluste gesondert berücksichtigen)
Calculation base P_{TAV} (switching losses should be considered separately)

Parameter: Stromflußwinkel Θ / Current conduction angle Θ



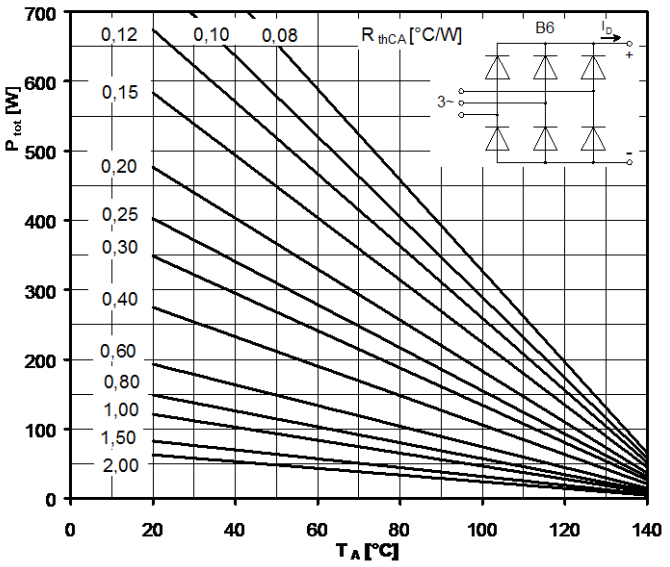


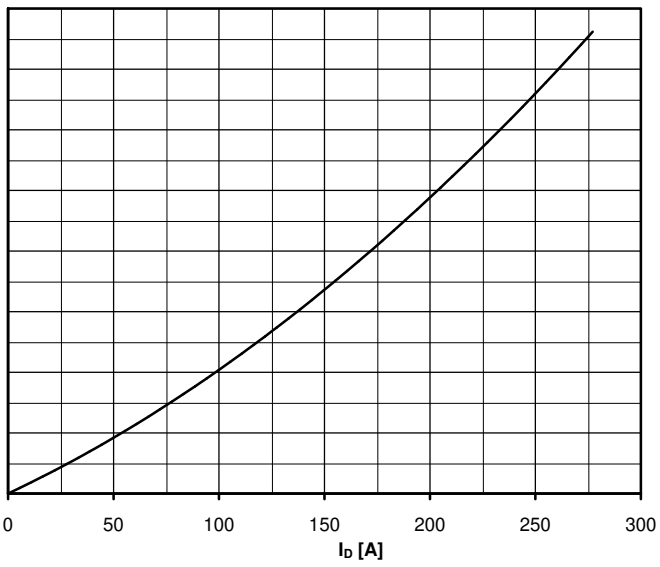
Höchstzulässiger Ausgangsstrom / Maximum rated output current I_D

B2- Zweipuls-Brückenschaltung / Two-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit P_{tot}

Parameter:
Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient R_{thCA}



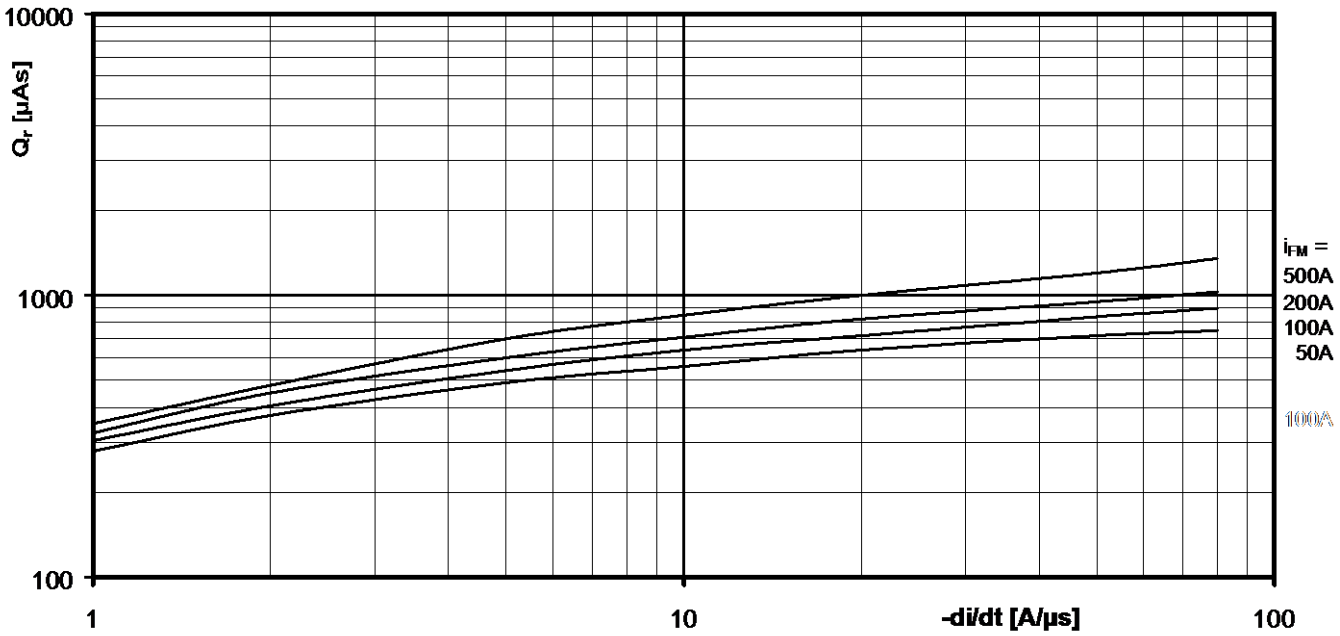


Höchstzulässiger Ausgangsstrom / Maximum rated output current I_D

B6- Sechspuls-Brückenschaltung / Six-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit P_{tot}

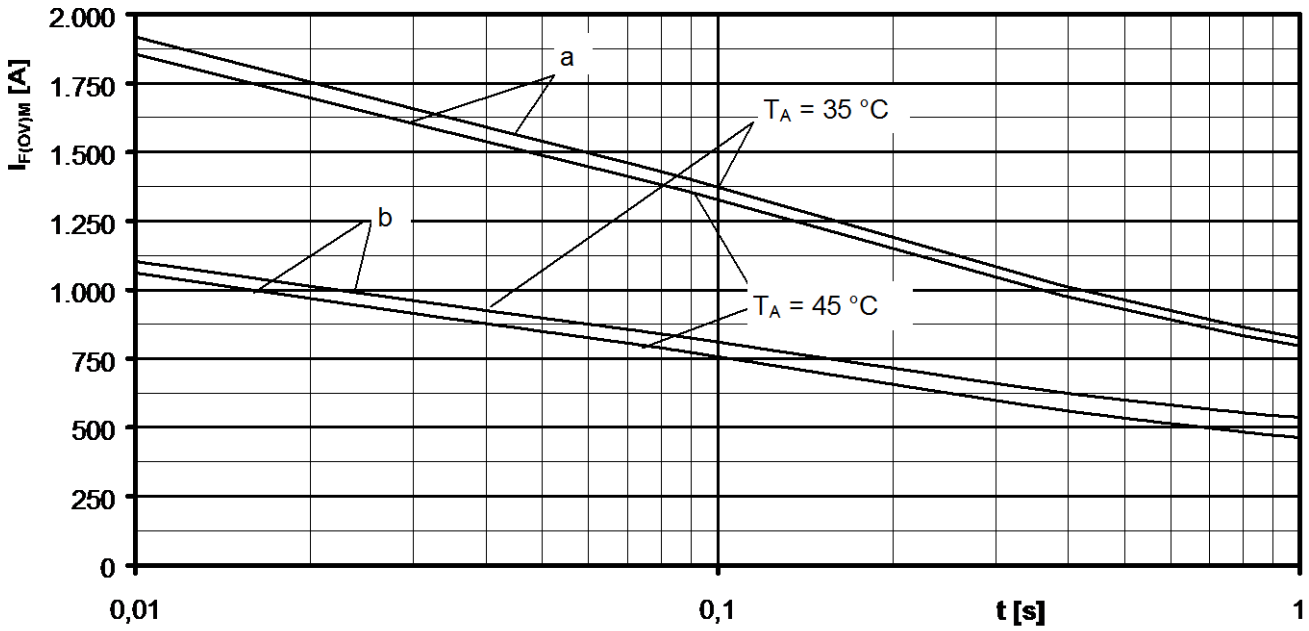
Parameter:
Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient R_{thCA}



Sperrverzögerungsladung / Recovered charge Q_r = f(-di/dt)

$T_{vj} = T_{vjmax}$, $v_R \leq 0{,}5\ V_{RRM}$, $v_{RM} = 0{,}8\ V_{RRM}$

Parameter: Durchlaßstrom / On-state current i_{FM}

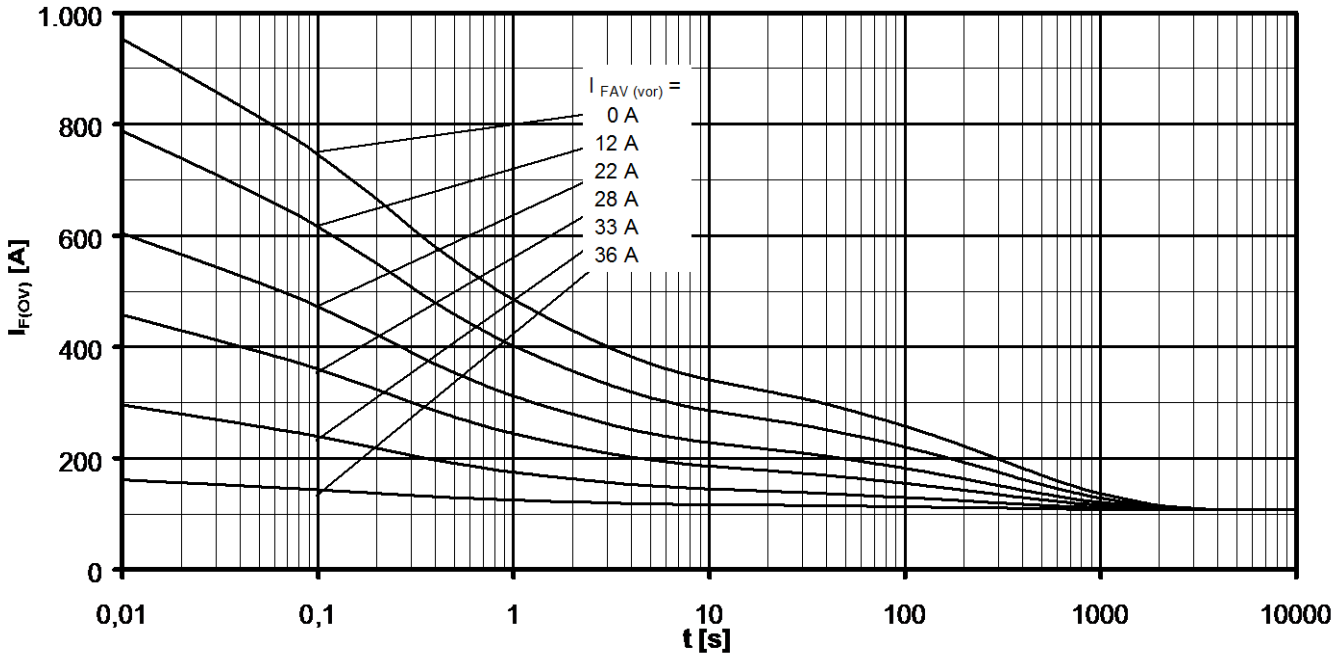


Grenzstrom je Zweig / Maximum overload on-state current per arm $I_{F(OV)M} = f(t)$, $v_{RM} = 0{,}8\ V_{RRM}$

a: Leerlauf / No-load conditions
b: Vorlaststrom je Zweig / Pre-load current per arm $I_{FAV(vor)} = I_{FAVM}$

T_a = 35°C, verstärkte Luftkühlung / Forced air cooling Kühlkörper / Heatsink type: KM14 (Papst 4650)

T_a = 45°C, natürliche Luftkühlung / Natural air cooling Kühlkörper / Heatsink type: KM14 (50W)

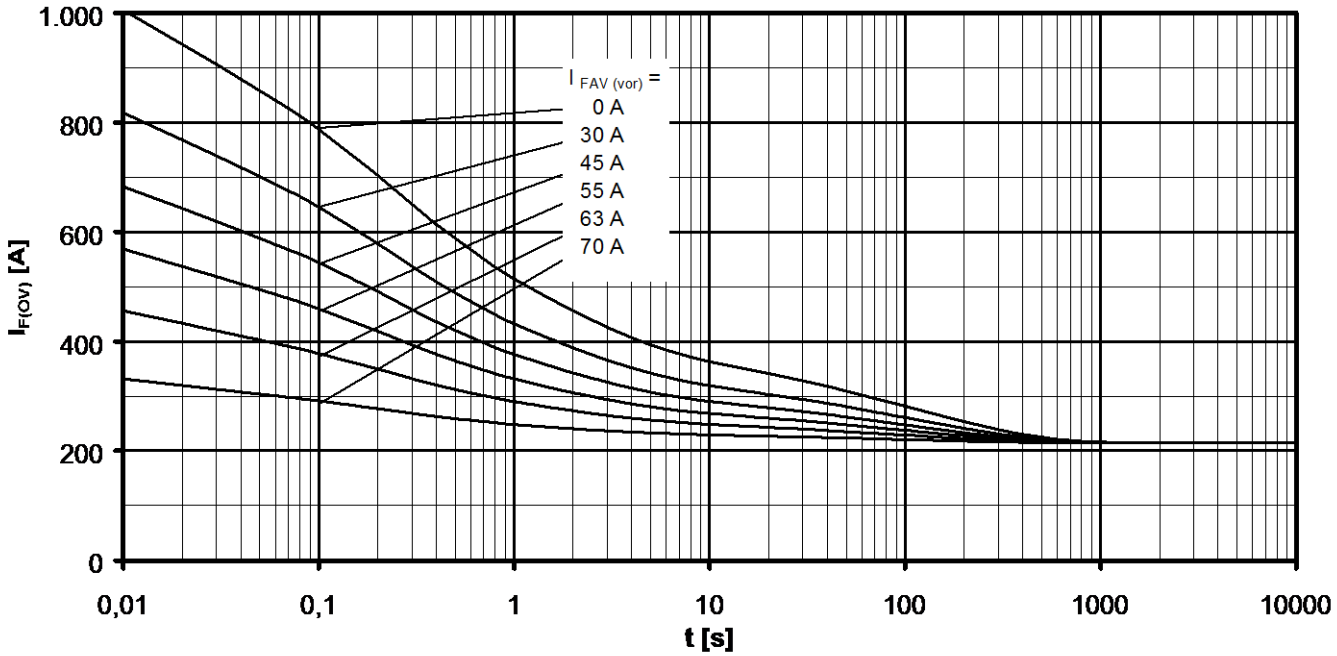


Überstrom je Zweig / Overload on-state current $I_{F(OV)}$

B6- Sechspuls-Brückenschaltung, 120° Rechteck / Six-pulse bridge circuit, 120° rectangular

Kühlkörper / Heatsink type KM14 (50W) Natürliche Kühlung bei / Natural cooling at T_A = 45°C

Parameter: Vorlaststrom je Zweig / Pre-load current per arm $I_{FAV(vor)}$



Überstrom je Zweig / Overload on-state current $I_{F(OV)}$

B6- Sechspuls-Brückenschaltung, 120° Rechteck / Six-pulse bridge circuit 120° rectangular

Kühlkörper / Heatsink type KM14 (Papst 4650) Verstärkte Kühlung bei / Forced cooling at T_A = 35°C

Parameter: Vorlaststrom je Zweig / Pre-load current per arm $I_{FAV(vor)}$